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Microsemi.

Power Matters[™]

120.00

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2N5333 (#23805)

Devil of Director

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Overview Diagrams

Electrical Rating Symbol Min Typ Max

Collector to Emitter Saturation Voltage V_{CE(sat)} 1.00

Maximum Electrical Rating	Symbol	Min	Тур	Max	Unit
Breakdown Voltage, Collector-Base (Emitter Open)	V _{BR(CBO)}			100.00	V
Collector Current (dc)	I _C			-2.00	А
Collector-Emitter Voltage (Base Open)	V _{CEO}			80.00	V
Emitter-Base Voltage (Collector Open)	V _{EBO}			6.00	V
Power Dissipation, Total	P _T			1.00	W

HFE

This part can be found in the following product categories:

- → Discretes → Transistors → BJT(BiPolar Junction Transistor) → PNP Transistor
- Non-Radiation Hardened Devices ▶ Transistors ▶ BJT(BiPolar Junction Transistor) ▶ PNP Transistor

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